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Impact of Carbon Impurities on Air Stability of MOCVD 2D-MoS₂

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Abstract: Metal–organic chemical vapor deposition (MOCVD) is a key method for scalable synthesis of two-dimensional transition metal dichalcogenide (2D-TMDC) layers. However, it faces several challenges, such as the unintentional co-deposition of carbon impurities resulting from the pyrolysis of metal–organic precursors. This study investigates the chemical features of carbon and its impact on the photoluminescence property and air stability of 2D-MoS₂. Using X-ray photoemission spectroscopy (XPS), it was found that the carbon impurities show characteristics similar to those of sp²-bonded graphitic carbon. Upon prolonged (20–40 weeks) exposure to the atmosphere, the incorporated carbon appears to react with 2D-MoS₂, forming a MoS₂−xCₓ solid solution. At the same time, a gradual decrease in the S/Mo ratio implies the formation of sulfur vacancies was also observed. These two processes lead to crystal degradation over time, as evidenced by the gradual quenching of the Raman and photoluminescence (PL) peaks. More detailed PL analyses suggest a charge transfer mechanism between sp²-carbon/2D-MoS₂ and 2D-MoS₂/air-adsorbates, which, in the short term, could alter PL emissions and appear to further intensify the degradation of 2D-MoS₂ in the long-term. The findings highlight the strong impact of unintentionally co-deposited carbon on the optical properties and air stability of MOCVD 2D-MoS₂ layers.

Keywords: 2D-MoS₂; metal–organic precursor; carbon impurities; photoluminescence; aging

1. Introduction

Two-dimensional transition metal dichalcogenides (2D-TMDCs) and their heterostructures have been utilized to demonstrate a variety of electronic and optoelectronic devices such as field-effect transistors (FET) [1], photodetectors [2], memory devices [3], light-emitting diodes (LED) [4], solar cells, sensors [5], etc. However, to transfer all these proof-of-concept devices into commercial applications, many challenges still have to be overcome. Some of them are developing scalable synthesis methods, robust layer transfer processes, as well as device-level issues such as high contact resistance and low carrier mobility [6,7]. Regarding synthesis, a variety of deposition techniques have been explored. These range from molecular beam epitaxy (MBE) [8,9], physical vapor deposition (PVD) [10–12], chemical vapor transport (CVT) [13,14], chemical vapor deposition (CVD) [15,16], and metal–organic chemical vapor deposition (MOCVD) [17–21]. MOCVD is known as an established scalable deposition method for compound semiconductors with industrial multi-wafer tools yielding superior homogeneity and reproducibility. However, optimal tool design, synthesis conditions and precursor chemistries [22] of MOCVD processes for TMDCs still have to be developed. In particular, reactive carbon radicals in the reaction chamber originating from the pyrolysis paths of metal–organic precursors [21,23] can lead to unintentional
co-deposition of carbon impurities. Carbon co-deposition has also been reported in the CVD of MoS\textsubscript{2}, originating from impurities present in the MoO\textsubscript{3} and S powders used as precursors [24]. The incorporation of carbon into 2D-MoS\textsubscript{2} during the MOCVD process, as well as some approaches to avoid it, have been reported [21,25–27]. For example, Schaef er et al. have shown that the addition of H\textsubscript{2} to the reaction chamber can reduce carbon incorporation into the 2D layer through the etching of the domain edges. The presence of carbon was confirmed by Raman spectroscopy measurement. Carbon-related peaks were found at around 1360 and 1600 cm\textsuperscript{−1}, in analogy to the D and G bands of graphene [28]. A reliable solution to fully mitigate carbon co-deposition is still under investigation. Moreover, in most cases, carbon-related Raman signatures have been the sole criterion for validating the presence of carbon. Lower concentrations may have been overlooked probably due to the relatively low sensitivity of Raman spectroscopy in comparison to other methods such as X-ray photoemission spectroscopy (XPS). Although these works have been dedicated to investigating the co-deposition of carbon during MOCVD, more detailed investigations are yet to be performed to fully comprehend its impact on the properties of 2D-TMDC layers. Vulnerability of 2D-TMDCs, both synthetic (obtained by, e.g., CVD, MOCVD, ALD (atomic layer deposition), etc.) and exfoliated from bulk single crystals against ambient-air exposure, has already been addressed in the literature. However, it was found that synthetic 2D-TMDCs typically possess a higher density of imperfections, such as grain boundaries, edge defects, point defects, impurities etc. [29–31]. This does not only degrade electrical properties, e.g., mobility in FET [6], but also turns the material more susceptible to surface reactions with atmosphere and hence to a faster degradation over time. For example, Gao et al. [32] investigated the ambient aging of CVD-MoS\textsubscript{2} grown on SiO\textsubscript{2}/Si. They have shown that severe oxidation occurs at grain boundaries. After one year, MoS\textsubscript{2} was found to be significantly degraded, evidenced by scanning electron microscopy (SEM) showing structural changes and cracking. Raman and PL spectra also revealed a serious quenching of intensity over time, a clear indication of a “reduced amount of emitting material”. Peto et al. [33] investigated the oxidation mechanism of 2D-MoS\textsubscript{2} obtained from single-crystal exfoliation via scanning tunneling microscopy/spectroscopy (STM/STS). The authors have shown that upon ambient exposure, O atoms tend to be spontaneously incorporated into the basal plane of MoS\textsubscript{2}. Individual S atoms are replaced with O which is consequently leading to a 2D-MoS\textsubscript{2}–O\textsubscript{x} solid solution. This oxidation process preserves the original crystal lattice with Mo sites in trigonal prismatic configuration. In other works, the role of substrate hydrophobicity [34] and ambient light [35] during the aging of 2D-TMDC layers has been investigated. To the best of our knowledge, the air stability of MOCVD 2D-TMDC layers related to the role of C impurities has not been reported in literature. In this work, we have systematically studied the chemical features of unintentionally co-deposited carbon impurities in MOCVD 2D-MoS\textsubscript{2} and their impact on the atmospheric aging behavior and photoluminescence property of these materials.

2. Materials and Methods

Two-dimensional-MoS\textsubscript{2} MOCVD. The 2D-MoS\textsubscript{2} layers were epitaxially grown in an AIXTRON MOCVD reactor. Sapphire (0001) with a nominal offcut of 0.2° towards m-plane was used as substrate. Prior to deposition, the sapphire was desorbed at 1050 °C in 200 hPa H\textsubscript{2} atmosphere for 15 min [36]. Depositions were performed at constant chamber pressure and temperature of 30 hPa and 825 °C, respectively, by H\textsubscript{2}S-free MOCVD. Di-tert-butyl sulfide (DTBS) and molybdenum hexacarbonyl (Mo(CO)\textsubscript{6}) were used as sulfur and molybdenum precursors, and N\textsubscript{2} as the carrier gas. The molar chalcogen/metal precursor ratio was kept at the constant value of ≈1000 for all depositions. Three different cool-down procedures after the growth step, namely, 2 K min\textsuperscript{−1} in N\textsubscript{2}/DTBS (Flow\textsubscript{N2}: 30,000 sccm; Flow\textsubscript{DTBS}: 20 µmol/min), ballistic (≈20 K min\textsuperscript{−1}) cool-down in N\textsubscript{2} and 2 K min\textsuperscript{−1} in N\textsubscript{2}, have been used, which are denoted as 2DTBS, BN2, and 2N2, respectively. Deposition took ≈6 h to obtain a nearly coalesced monolayer (ML) with sparse bilayer (BL) and trilayer (TL) nucleation.
X-Ray Photoemission Spectroscopy (XPS). For XPS measurements, a Versa Probe 5000 tool manufactured by Physical Electronics was used. Monochromatic X-rays are generated by an Al Kα source with an excitation energy of 1486.6 eV. The low-power mode with 25 W and an X-ray spot diameter of about 100 µm was used. To compensate for charging effects, electron neutralization was performed with a neutralizer emission current of 20 µA and a neutralizer bias of 1.37 eV. The Au 4f peak at 84.0 eV was used as the reference to calibrate the binding energy (BE) scale of XPS spectra. Survey scans were performed by 187 eV pass energy. Two high-resolution scans with pass energy set at 10 and 20 eV were performed with step sizes of 0.1 and 0.2 eV, respectively. The latter one was used to carry out quantitative analyses. Regarding the XPS core level analyses, a Shirley function for background subtraction followed by Voigt lineshape deconvolution was used. To characterize the as-deposited 2D layers, they have been stored in an N2 box to minimize atmospheric exposure. The samples were unboxed just before measurement. After the first measurement, the batch of samples was kept in gel boxes and additionally wrapped in Al foil in a clean-room atmosphere to rule out any effect from ambient light over the course of several weeks, during which the measurements were repeated.

Photoluminescence and μ-Raman Spectroscopy. The as-deposited and aged samples were characterized using PL and μ-Raman spectroscopy. Non-resonant Raman and PL spectra were acquired at room temperature using a WiTec confocal Raman microscope equipped with a solid-state 532 nm laser. The laser line was focused on the samples by a 100× microscope objective lens. The collected light was dispersed by 300 grooves/mm and 1800 grooves/mm gratings for PL and μ-Raman measurements, respectively. To prevent laser-induced local heating, the laser power was kept at a low value of 0.7 mW. All PL spectra were fitted using pseudo-Voigt line shapes for A−, A0, and B emissions.

Scanning Electron Microscopy (SEM). Morphological characterization of as-deposited and aged samples was performed by scanning electron microscopy (SEM, Zeiss Sigma, Oberkochen, Germany). To quantify the contribution of ML, BL and TL domains as well as the total surface coverage, image processing was performed using the software ImageJ [37].

3. Results and Discussion
3.1. Characterization of As-Deposited 2D-MoS2 Layers

Segmented SEM pictures of the as-deposited samples are shown in Figure 1a(i)–(iii). Analyses of multiple images using ImageJ reveal similar ML and BL coverage for all 2DTBS, 2N2, and BN2 samples. Values for ML and BL are found to be ≈42% and ≈48%, respectively. All three samples also show a small amount of TL nucleation of about 3% (layer coverages of multiple samples calculated by ImageJ are given in Figure S1a). SEM investigations revealed the uniformity and reproducibility of the 2D layers. We chose three different cool-down conditions in order to produce samples that differ primarily in carbon content while maintaining similar morphology as well as ML and BL coverage. By employing identical growth parameters and only altering the cool-down conditions, we ensure reliable comparisons between samples, which are discerned only by the different co-deposited carbon content.

PL maps of A exciton emission intensity of the as-deposited samples are shown in Figure 1b(i)–(iii). The PL intensity varies considerably between the three different as-deposited samples; 2DTBS and 2N2 show the lowest and highest PL intensity, respectively; this can be linked to the chemical composition of the layers, which will be discussed in more detail later in this section. The corresponding Raman spectra of the samples are also shown in Figure 1c; the characteristic MoS2 Raman peaks, namely, E2g and A1g, are located at ≈383.8 and ≈405.3 cm−1, respectively. These are the first-order Raman modes associated with in-plane and out-of-plane vibrations, respectively [38]. The distance between the two peaks is found to be 21.5 cm−1 and confirms that the surface coverage is dominated by ML and BL contributions in agreement with the SEM analyses [39].
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Figure 1. (a) Segmented SEM images of as-deposited samples with different cool-down condition (2DBS, BN2 and 2N2). The white, grey and black colors represent sapphire, ML and BL, respectively; and (b) corresponding PL map of A exciton intensity extracted from a 5 µm × 5 µm area. (c) Raman spectra of as-deposited samples.

XPS analyses of the as-deposited samples (before exposure to the atmosphere) are given in Figure 2. Since the C1s peak is not dominated by adventitious carbon, the peaks were calibrated with respect to the Al2p peak, explained in detail in the supporting information. The survey scans shown in Figure 2a are dominated by Mo3d, S2p, Al2p, Al2s, C1s and O1s. Mo, S, and C can be ascribed to the MOCVD process. Al and O are attributed to the Al2O3 substrate. Due to the desorption step prior to deposition (see Section 2), negligible carbon contamination on the sapphire is. It should be noted that the substrate signals are detectable because of the ultra-low thickness of the 2D-MoS2, which is 1–3 ML (=0.72–2.16 nm) [40]. The Mo3d-S2p and S2p core levels are shown in Figure 2c(i) and (ii), respectively. The corresponding curves obtained from a reference MoS2 bulk single crystal (HQ-Graphene, purity > 99.995%), denoted as SC, are also shown for comparison. The binding energy difference between Mo3d5/2 and S2p3/2 (\(\Delta E_{\text{Mo3d-S2p}}\)) is found to be 67.1 eV in the single-crystal MoS2, which is in agreement with the literature [41,42]. The corresponding values of \(\Delta E_{\text{Mo3d-S2p}}\) for 2DTBS, 2N2, and BN2 samples are extracted as 67.1, 67.2, and 67.2 eV, respectively. Considering the binding energy difference in addition to the absolute binding energy values makes XPS analyses more reliable because the absolute values can be shifted as a result of, e.g., doping [41], impurities [21], and charging [43]. The core levels verify the formation of pure MoS2 with neither oxide nor carbide components being detected.

The zoomed-in survey spectra, including the Mo3d, S2p, and C1s core levels, along with the S/Mo stoichiometry ratio and the carbon concentration in atomic%, are given in Figure 2b(ii). The stoichiometries were determined by evaluating the ratio between the S2p and Mo3d peak areas and then were normalized to the stoichiometry of the reference single-crystal MoS2 [41,44] assumed to have an S/Mo ratio of 2.0. The carbon atomic percentage obtained from the quantitative analysis represents the contribution of the C-C bond shown in blue in Figure 2b(i). The XPS analysis data and the PL intensity of as-deposited samples are summarized in Table 1.

\[\Delta E_{\text{Mo3d-S2p}} = 67.1 \text{ eV} \]

\[\approx \text{0.72–2.16 nm} \]

\[\text{SC} \]
* The values obtained by weighted averaging the histogram plot of the PL intensity maps (Figure S4).

Figure 2. XPS analysis: (a) survey spectra, (b) fitted high-resolution C1s core levels (i), and zoomed-in survey spectra showing S2p, Mo3d and C1s peaks and the corresponding carbon (C-C bond) atomic percentage and S/Mo ratio, obtained from quantitative analysis (ii), (e) high-resolution Mo3d-S2s (i) and S2p core levels (ii); the single-crystal (SC) core levels are also shown for comparison, (iii) XPS C1s core level of bare sapphire stored in cleanroom atmosphere and that of the as-deposited 2DTBS sample, displaying the C-C bond in green and blue, respectively.

Table 1. Binding energy, carbon concentration, PL A exciton intensity of as-deposited samples and the single-crystal reference.

<table>
<thead>
<tr>
<th></th>
<th>Mo 3d5/2 (eV)</th>
<th>S 2p3/2 (eV)</th>
<th>Carbon (Atom. %)</th>
<th>PL A Intensity * (cts)</th>
</tr>
</thead>
<tbody>
<tr>
<td>SC</td>
<td>229.6</td>
<td>162.5</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>2DTBS</td>
<td>228.6</td>
<td>161.5</td>
<td>5</td>
<td>57.52</td>
</tr>
<tr>
<td>2N2</td>
<td>228.6</td>
<td>161.4</td>
<td>3</td>
<td>87.56</td>
</tr>
<tr>
<td>BN2</td>
<td>228.7</td>
<td>161.5</td>
<td>4</td>
<td>66.4</td>
</tr>
</tbody>
</table>

* The values obtained by weighted averaging the histogram plot of the PL intensity maps (Figure S4).

The S/Mo stoichiometry ratios for all three samples deviate slightly relative from the ideal value of 2.0, indicating the deposition of sulfur-rich or sulfur-deficient 2D-MoS2 layers in comparison to the exfoliated single-crystal counterpart [30,45–47]. It is noteworthy that the excess sulfur in the 2DTBS and BN2 samples with an S/Mo ratio higher than 2.0 suggests that some sulfur atoms are present in a different chemical environment other than the Mo-S bond [10]. However, the concentration of these species is not high enough to be distinguished in the S2p core levels (see Figure S2a).

To analyze the carbon species found in our layers in more detail, the high-resolution XPS spectra of the C1s core levels were deconvoluted. The fitted spectra constitute C-C, C-O, and C=O bonds, with the C-C bond dominating the spectra (Figure 2b(ii)). It was found that the full width at half-maximum (FWHM) values of the C-C-bond-related peak (blue in Figure 2b(ii)) are 1.02 eV, 1.10 eV and 1.08 eV for 2DTBS, 2N2 and BN2, respectively. In comparison, the FWHM values of the carbon peak measured on single-crystal MoS2 and bare sapphire (Figure S2b(ii),(iii)), which originate only from adventitious carbon, were found to be 1.49 eV and 1.48 eV, respectively, showing ≈40% increase relative to the C1s peak (C-C bond) of as-deposited samples. The sharper C1s peak in the MOCVD 2D-MoS2 samples is an indication of a more structured carbon species in these 2D layers.

Moreover, the C1s lineshape shows a broader asymmetric tail toward higher binding energies, which is typical for graphite and graphene [48–53]. On the other hand, the binding energy difference between the dominant C1s peak (C-C bond) and Al2p (ABE_{C1s-Al2p}) on
bare sapphire (Figure S2b(i),(ii)) is found to be 209.8 eV; yet $\Delta BE_{C1s-Al2p}$ for 2DTBS, 2N2 and BN2 is measured to be 209.2, 209.2 and 209.3 eV, respectively. The systematic shift of the C1s peak towards lower values by $\approx 0.6$ eV in the MOCVD samples moves it close to the typical BE position for the sp$^2$-hybridized C bond in graphene and graphite [48,50,51,54–56]. As an example, the C1s core level of sapphire stored in the atmosphere and that of the as-deposited 2DTBS sample are shown in Figure 2c(iii); the C-C bond in the 2DTBS sample features a narrower peak located at lower BE relative to the C-C bond in bare sapphire. Thus, it can be concluded that the carbon species incorporated into 2D-MoS$_2$ layers during MOCVD tend to show more graphitic characteristics than those of adventitious carbon. It is worth mentioning that the wide-range Raman spectra of the samples do not show the carbon-related peaks expected at $\approx 1360$ and $\approx 1600$ cm$^{-1}$. (Figure S3)

The variation of PL intensities in the as-deposited samples shown as A exciton PL maps in Figure 1b(i)–(iii) can be attributed to the concentration of sp$^2$-C impurities in these samples. The A exciton peak consists of the neutral A$^0$ exciton and the negatively charged A$^-$ trion with emissions at around 1.89 eV and 1.86 eV, respectively [21,57]. A$^0$ usually dominates the spectra because of reduced non-radiative recombination probability [58]. A$^-$ appears when MoS$_2$ has a significant electron concentration in the conduction band (n-type characteristic), which can be induced by, e.g., sulfur vacancies, chemical doping [59], [60], or strain [61,62]. It can be seen that the PL intensity is clearly reduced by the increase in the sp$^2$-C concentration (see Table 1). Accordingly, samples 2DTBS and 2N2 with five and three atomic% carbon feature the lowest and highest intensity, respectively. It has already been reported that 2D-MoS$_2$ PL attenuation occurs in the presence of carbon, e.g., if MoS$_2$ forms a heterostructure with graphene quantum dots (GQD) or graphene [57,63]. This observation is attributed to the transfer of electrons from GQD/graphene to MoS$_2$, which leads to an attenuation in A$^0$ exciton emissions [63–65].

3.2. Aging of MOCVD 2D-MoS$_2$

All samples were exposed to ambient air for 40 weeks, with several XPS measurements performed during this time span. The FWHM values of XPS Mo$_3d_{5/2}$ and S$_2p_{3/2}$ given in Figure 3b(i) show a gradual increase, which is an indication of the reduced crystal quality of the 2D-MoS$_2$ layers. This could be due to various factors, such as accumulation of structural defects, impurities, oxidation, etc.

Moreover, desulfurization has also been evidenced by XPS analysis; the S:Mo stoichiometry ratio measured over the 40-week period shows a gradual decrease (Figure 3b(ii)). The highest degree of sulfur loss is detected for the 2DTBS sample, with $\approx 8\%$. XPS Mo$_3d_{5/2}$ and S$_2p_{3/2}$ core levels of the 40-week-aged samples (Figure 3a(i) and (iii)) do not indicate any oxidation after 40 weeks. Oxidation would be identified by additional shoulders located towards higher binding energies relative to the Mo$_{3d_{5/2}}$ and Mo$_{3d_{3/2}}$ peaks of MoS$_2$ caused by Mo-O bonds. Possibly, these features lie below the sensitivity limit of the XPS tool, which is a $\approx 1$ atomic % concentration. However, in some other works utilizing XPS measurements, the formation of significant densities of transition metal oxides after a few weeks was reported [32,66]. The fact that the concentration of oxide species did not reach the XPS detection limit after 40 weeks might be attributed to the higher stability of the 2D layers investigated in this work. Such higher stability could be due to the (nearly) coalesced morphology of the layers and the fact that the stability is especially dependent on the density of defects (including edge defects) in the pristine material [33,67].

It should be noted that the number of oxide compounds or O$_2$/H$_2$O on the surface/edges of 2D-MoS$_2$ layers may not reach the XPS-detectable level (which is $\approx 1$ atomic%), although physiosorbed or chemisorbed O$_2$/H$_2$O species are likely present. Previous studies, such as the work by Peto et al. [33], utilizing a more sensitive method (STM/STS), have demonstrated the formation of atomic level solid-solution-type 2D-MoS$_{2-x}$O$_x$ formed during ambient exposure of single-crystal MoS$_2$ while XPS failed to detect any covalent oxygen bonding to the top sulfur atoms or the formation of oxidized MoO$_3$ areas. Addi-
tionally, the presence of adsorbed \( \text{O}_2/\text{H}_2\text{O} \) on 2D-MoS\(_2\) can be confirmed by Raman and PL spectroscopy.

![Figure 3](image-url)

**Figure 3.** (a) XPS analysis of 40-week-aged samples; (i) Mo\(_{3d}\)-S\(_{2s}\) and (iii) S\(_{2p}\) core levels lineshape and fitted (ii) Mo\(_{3d}\)-S\(_{2s}\) and (iv) S\(_{2p}\) high-resolution spectra. (b) (i) FWHM of Mo3d\(_{5/2}\) peak and (ii) S:Mo stoichiometry ratio variation over the course of 40 weeks. (c) (i) Raman spectra and (ii) the corresponding \( A_{1g} \) peak position over the course of 20 weeks; for the Raman signals, the number of accumulations is 20 for all the measurements.

Moreover, the XPS core levels show a minor yet clearly detectable amount of carbide species after 40 weeks of ambient exposure for the 2DTBS and BN2 samples. These species appeared as a shoulder peak towards lower binding energies of both Mo\(_{3d}\) and S\(_{2p}\) core levels (marked by the asterisk symbol in Figure 3a(i),(iii)). Deconvoluted high-resolution XPS spectra of the Mo\(_{3d}\)_\(-\)-S\(_{2s}\) (Figure 3a(ii),(iv)), and C\(_{1s}\) (Figure S2c) core levels of samples 2DTBS and BN2 revealed that the newly emerged shoulder peak can be attributed to Mo\(_{2-x}\)\(C\)_\(_x\). The emerged carbide peaks are located at binding energies which are 0.85, 0.65, and 0.86 eV lower than those of Mo3d\(_{5/2}\), S2p\(_{1/2}\), and C\(_{1s}\) (C-C bond) peaks, respectively, which is in good agreement with the values reported in the literature [68,69]. The formation of Mo\(_{2-x}\)\(C\)_\(_x\) suggests that sp\(^2\)-C tends to react with Mo\(_2\) over time. The atomic concentrations of Mo\(_{2-x}\)\(C\)_\(_x\) species detected in samples 2DTBS and BN2 were found to be \( \approx 12\% \) and \( \approx 7\% \), respectively. The XPS O\(_{1s}\) peak, as well as the SEM morphology of aged layers, are given in Figure S3.

The formation of carbide species upon exposure of 2D-TMDC layers to ambient is potentially exclusive to the MOCVD layers, in which sp\(^2\)-carbon impurities are co-deposited due to the use of metal–organic precursors in this method.

Raman spectra of the samples exposed to the atmosphere measured at different time intervals are shown in Figure 3c(i); the intensity of the characteristic \( E_{2g} \) and \( A_{1g} \) peaks for all three samples show a gradual decrease over time, which is an indication of layer degradation. Moreover, the \( A_{1g} \) peak exhibits a gradual shift toward higher frequencies (Figure 3c(ii)); this can be attributed to the adsorption of air molecules on the surface, which restrain the out-of-plane vibrational mode and introduce compressive strain along the c direction of the unit cell [70].

The fitted PL spectra for the as-deposited samples after one week and after ten weeks of exposure to the atmosphere are given in Figure 4a. As explained before, in the as-deposited
samples, the intensity of the trion peak $A^-$ and, accordingly, the $I_{A^-}/I_{A^0}$ ratio increases with a rising $sp^2$-C concentration.

Figure 4. (a) Fitted PL spectra of (i) as-deposited, (ii) one-week-aged and (iii) 10-week-aged samples showing the $A^-$ trion, $A^0$ and B excitons peaks in orange, green and purple color, respectively, as well as the $A^-/A^0$ intensity ratio for as-deposited and one-week-aged samples. (b) PL A exciton (i) intensity and (ii) energy position over the course of 20 weeks of atmospheric aging (with dashed line as a guide to the eye).

Interestingly, in the one-week-aged samples, unlike their as-deposited counterparts, it was observed that the $I_{A^-}/I_{A^0}$ ratio is inversely correlated to $sp^2$-C concentration. This observation can be attributed to the interaction of the 2D-MoS$_2$ film with the ambient atmosphere. The accumulation of negative charge in the 2D-MoS$_2$ transferred from the $sp^2$-C (as described before) makes the adsorption of $O_2/H_2O$ to the 2D-MoS$_2$ energetically more favorable [34]. The enhanced adsorption results from a probably reduced work function (WF) of 2D-MoS$_2$ due to the charge transfer n-doping by $sp^2$-C [71]. Following that, adsorbed $H_2O/O_2$ molecules deplete the negative charges, leading to a reduced $A^-$ recombination and enhanced $A^0$ exciton emissions.

The PL of 10-week-aged samples (Figure 4a(iii)) shows a significant quenching for all three samples, which is an indication of degraded layers and the reduction in emitting materials regardless of the concentration of $sp^2$-C.

The PL intensity of the A exciton and its energy position over the course of 20 weeks of ambient exposure is presented in Figure 4b(i) and (ii), respectively. Exciton emission energies show a gradual blue shift over a period of $\approx$15 weeks. After that, especially for the 2DTBS sample (with the highest carbon content), a slight red-shift occurs. The PL emission
blue-shift is consistent with the presence of H₂O/O₂ adsorbates at the surface and the consequent p-doping of MoS₂ layers [72] and confirms the trend of the gradual blue-shift of the Raman A₁₅ vibrational mode discussed previously. The consecutive red shift might be attributed to the general degradation mechanisms of MoS₂ exposed to the atmosphere.

The atmospheric aging of MOCVD 2D-MoS₂ involves multiple factors that can either enhance or quench the PL emission. For example, the adsorption of O₂/H₂O air molecules can lead to the p-doping of MoS₂, resulting in an increase in PL emissions [73,74]. Conversely, the aging process can also introduce various defects, acting as non-radiative recombination centers. Depending on the dominant factor at different stages of aging, the PL emissions can either be enhanced or exhibit a drop in intensity. An illustrative example is observed in the 2DTBS sample, which has the highest sp²-C content. During the early stages of aging, this sample shows an enhancement in the PL emission, suggesting the dominant effect of p-doping; however, after 20 weeks, a more pronounced quenching of the PL is observed in comparison to the other samples. This quenching can be attributed to the increased formation of structural defects, as supported by XPS analysis revealing the presence of carbide species. The dominant mechanisms defining PL emissions during atmospheric aging of MOCVD 2D-MoS₂ are schematically presented in Figure 5.

![PL Modulation Mechanisms in Aging MOCVD 2D-MoS₂](image)

**Figure 5.** Photoluminescence (PL) intensity modulation mechanisms during atmospheric aging of MOCVD 2D-MoS₂.

### 4. Conclusions

In summary, we have investigated the photoluminescence property and air stability of nearly coalesced MOCVD 2D-MoS₂ layers, considering the role of unintentionally co-deposited carbon impurities. The characteristics and impact of incorporated carbon have been studied using XPS and PL characterization and revealed its graphitic sp²-C character. Carbon impacts the photoluminescence properties of 2D-MoS₂ by effective n-type doping, facilitating a charge transfer between 2D-MoS₂ and atmospheric adsorbates after exposure to air. It is especially notable that these effects are observed for C concentrations lying below the detection limit of Raman spectroscopy. O₂/H₂O adsorption was evidenced by PL and Raman A₁₅ vibrational mode blue shifts. On a timescale of 20–40 weeks, sp²-C tends to react with 2D-MoS₂ and forms MoS₂₋ₓCx. However, the precise location of impurities and adsorbates, as well as the exact chemical reactions, are not known and yet to be more thoroughly investigated, e.g., by more sensitive experimental methods (e.g., STM/STS). Moreover, it was found that even after 40 weeks of exposure, the 2D layers studied in this work did not show any oxidation detectable by XPS measurement. However, both PL and Raman spectroscopy of the aged layers indicated a clear drop in intensity, regardless of their initial carbon concentration, which is an indication of crystal degradation.
Supplementary Materials: The following supporting information can be downloaded at: https://www.mdpi.com/article/10.3390/surfaces6040025/s1, Figure S1: extended SEM analyses of as-deposited layers; Figure S2: fitted high-resolution of (a) Mo3d-S2s and S2p core levels of as-deposited samples, (b) Al2p and C1s core levels of bare sapphire and C1s core level of single crystal MoS2; (c) C1s core levels of 40-week-aged 2DBS and BN2 samples; Figure S3: XPS O1s spectra of as-deposited, 20-week- and 40-week-aged samples, as well as SEM of 40-week-aged layers. Figure S4: extended μ-Raman spectra of as-deposited samples and Figure S5: distribution of A0 PL intensity, obtained from the PL maps given in Figure 1 [21,23,32,36,75–77].

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References


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